

55N06

主要参数 MAIN CHARACTERISTICS

I_D	55 A
V_{DS}	60 V
$R_{DS(on)}$ (@ $V_{GS}=10V$)	22 m Ω
Q_g	34 nc

用途

- 高频开关电源
- 电子镇流器
- UPS 电源

产品特性

- 低栅极电荷
- 低 C_{RSS} (典型值 20pF)
- 开关速度快
- 产品全部经过雪崩测试
- 高抗 dv/dt 能力
- RoHS 产品

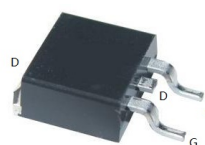
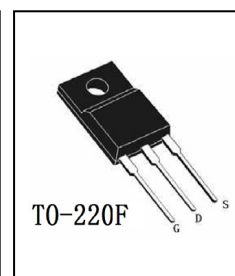
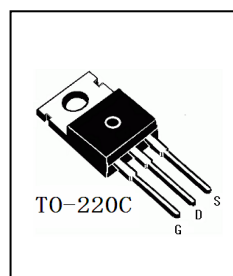
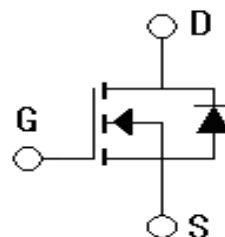
APPLICATIONS

- High efficiency switch mode power supplies
- Electronic lamp ballasts based on half bridge
- UPS

FEATURES

- Low gate charge
- Low C_{RSS} (typical 20pF)
- Fast switching
- 100% avalanche tested
- Improved dv/dt capability
- RoHS product

封装 Package



产品中有毒有害物质或元素的名称及含量

部件名称 (含量要求)	有害物质或元素					
	铅 (Pb)	汞 (Hg)	镉 (Cd)	六 价 铬 (Cr(VI))	多溴联苯 (PBB)	多溴二苯醚 (PBDE)
	≤0.1%	≤0.1%	≤0.01%	≤0.1%	≤0.1%	≤0.1%
引线框	○	○	○	○	○	○
塑封树脂	○	○	○	○	○	○
管 芯	○	○	○	○	○	○
内引线	○	○	○	○	○	○
焊 料	×	○	○	○	○	○
说 明	○：表示该元素的含量在 SJ/T11363-2006 标准的限量要求以下。 ×：表示该元素的含量超出 SJ/T11363-2006 标准的限量要求。 目前产品的焊料中含有铅 (Pb) 成分，但属于欧盟 RoHS 指令豁免范围。					

绝对最大额定值 ABSOLUTE RATINGS ($T_c=25^{\circ}\text{C}$)

项 目 Parameter	符 号 Symbol	数 值 Value		单 位 Unit
		55N06C/D	55N06F	
最高漏极-源极直流电压 Drain-Source Voltage	V_{DSS}	60		V
连续漏极电流 Drain Current -continuous	I_D $T=25^{\circ}\text{C}$ $T=100^{\circ}\text{C}$	55	55*	A
		33.0	33.0*	A
最大脉冲漏极电流(注 1) Drain Current – pulse (note 1)	I_{DM}	220*		A
最高栅源电压 Gate-Source Voltage	V_{GSS}	± 20		V
单脉冲雪崩能量(注 2) Single Pulsed Avalanche Energy (note 2)	E_{AS}	938		mJ
雪崩电流(注 1) Avalanche Current (note 1)	I_{AR}	55		A
重复雪崩能量 (注 1) Repetitive Avalanche Energy (note 1)	E_{AR}	12		mJ
二极管反向恢复最大电压变化速率 (注 3) Peak Diode Recovery dv/dt (note 3)	dv/dt	7.0		V/ns
耗散功率 Power Dissipation	P_D $T_c=25^{\circ}\text{C}$ -Derate above 25°C	103.8	56	W
		0.83	0.45	W/ $^{\circ}\text{C}$
最高结温及存储温度 Operating and Storage Temperature Range	T_J, T_{STG}	$-55 \sim +175$		$^{\circ}\text{C}$
引线最高焊接温度 Maximum Lead Temperature for Soldering Purposes	T_L	300		$^{\circ}\text{C}$

*漏极电流由最高结温限制

*Drain current limited by maximum junction temperature

电特性 ELECTRICAL CHARACTERISTICS

项 目 Parameter	符 号 Symbol	测试条件 Tests conditions	最小 Min	典型 Typ	最大 Max	单位 Units
关态特性 Off –Characteristics						
漏—源击穿电压 Drain-Source Voltage	BV_{DSS}	$I_D=250\mu A, V_{GS}=0V$	60	-	-	V
击穿电压温度特性 Breakdown Voltage Temperature Coefficient	$\Delta BV_{DSS}/\Delta T_J$	$I_D=250\mu A$, referenced to $25^\circ C$	-	0.6	-	V/ $^\circ C$
零栅压下漏极漏电流 Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=60V, V_{GS}=0V, T_C=25^\circ C$	-	-	10	μA
		$V_{DS}=48V, T_C=125^\circ C$	-	-	100	μA
正向栅极体漏电流 Gate-body leakage current, forward	I_{GSSF}	$V_{DS}=0V, V_{GS}=30V$	-	-	100	nA
反向栅极体漏电流 Gate-body leakage current, reverse	I_{GSSR}	$V_{DS}=0V, V_{GS}=-30V$	-	-	-100	nA
通态特性 On-Characteristics						
阈值电压 Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D=250\mu A$	2.0	-	4.0	V
静态导通电阻 Static Drain-Source On-Resistance	$R_{DS(ON)}$	$V_{GS}=10V, I_D=27.5A$	-	17	22	m Ω
正向跨导 Forward Transconductance	g_{fs}	$V_{DS}=40V, I_D=27.5A$ (note 4)		30	-	S
动态特性 Dynamic Characteristics						
输入电容 Input capacitance	C_{iss}	$V_{DS}=25V,$ $V_{GS}=0V,$ $f=1.0MHz$	-	900		pF
输出电容 Output capacitance	C_{oss}		-	430		pF
反向传输电容 Reverse transfer capacitance	C_{rss}		-	80		pF

电特性 ELECTRICAL CHARACTERISTICS

开关特性 Switching Characteristics							
延迟时间 Turn-On delay time	$t_d(\text{on})$	$V_{DD}=30V, I_D=55A, R_G=50\Omega$ (note 4, 5)	-	40	-	ns	
上升时间 Turn-On rise time	t_r		-	100	-	ns	
延迟时间 Turn-Off delay time	$t_d(\text{off})$		-	90	-	ns	
下降时间 Turn-Off Fall time	t_f		-	80	-	ns	
栅极电荷总量 Total Gate Charge	Q_g	$V_{DS}=48V$, $I_D=55A$ $V_{GS}=10V$ (note 4, 5)	-	34	45	nC	
栅-源电荷 Gate-Source charge	Q_{gs}		-	7	-	nC	
栅-漏电荷 Gate-Drain charge	Q_{gd}		-	17	-	nC	
漏-源二极管特性及最大额定值 Drain-Source Diode Characteristics and Maximum Ratings							
正向最大连续电流 Maximum Continuous Drain-Source Diode Forward Current	I_S		-	-	55	A	
正向最大脉冲电流 Maximum Pulsed Drain-Source Diode Forward Current	I_{SM}		-	-	220	A	
正向压降 Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=55A$	-		1.4	V	
反向恢复时间 Reverse recovery time	t_{rr}	$V_{GS}=0V, I_S=55A$ $di_F/dt=100A/\mu s$ (note 4)	-	50	-	ns	
反向恢复电荷 Reverse recovery charge	Q_{rr}		-	80	-	μC	

热特性 THERMAL CHARACTERISTIC

项 目 Parameter	符 号 Symbol	最大 Max		单 位 Unit
		55N06C/D	55N06F	
结到管壳的热阻 Thermal Resistance, Junction to Case	$R_{th(j-c)}$	1.20	2.22	$^{\circ}C/W$
结到环境的热阻 Thermal Resistance, Junction to Ambient	$R_{th(j-A)}$	62.5	62.5	$^{\circ}C/W$

注释:

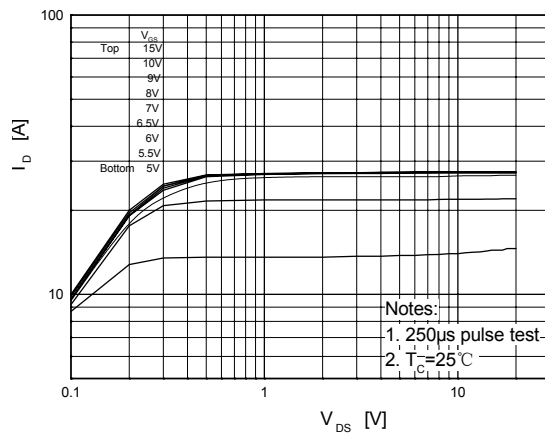
- 1: 脉冲宽度由最高结温限制
- 2: $L=0.4mH, I_{AS}=55A, V_{DD}=25V, R_G=25\Omega$, 起始结温 $T_J=25^{\circ}C$
- 3: $I_{SD} \leq 55A, di/dt \leq 300A/\mu s, V_{DD} \leq BV_{DSS}$, 起始结温 $T_J=25^{\circ}C$
- 4: 脉冲测试: 脉冲宽度 $\leq 300\mu s$, 占空比 $\leq 2\%$
- 5: 基本与工作温度无关

Notes:

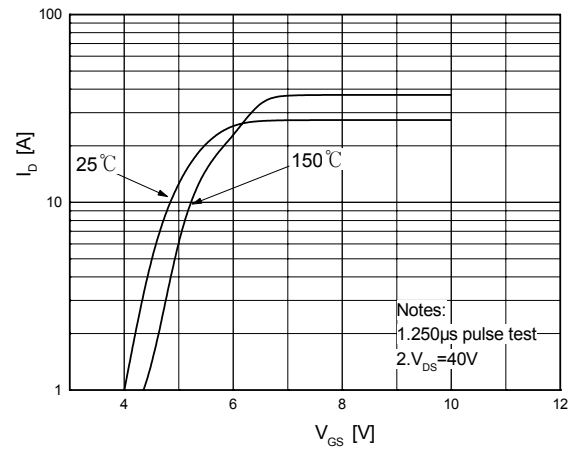
- 1: Pulse width limited by maximum junction temperature
- 2: $L=0.4mH, I_{AS}=55A, V_{DD}=25V, R_G=25\Omega$, Starting $T_J=25^{\circ}C$
- 3: $I_{SD} \leq 55A, di/dt \leq 300A/\mu s, V_{DD} \leq BV_{DSS}$, Starting $T_J=25^{\circ}C$
- 4: Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$
- 5: Essentially independent of operating temperature

特征曲线 ELECTRICAL CHARACTERISTICS (curves)

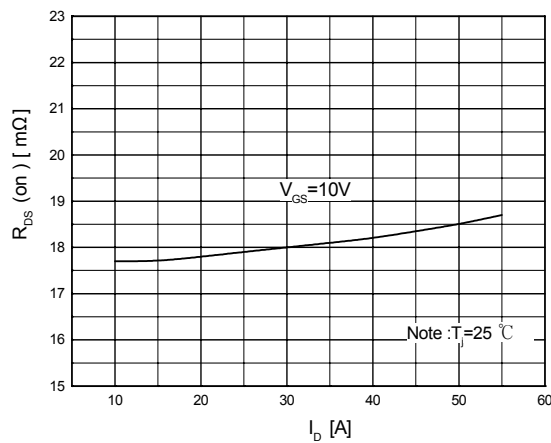
On-Region Characteristics



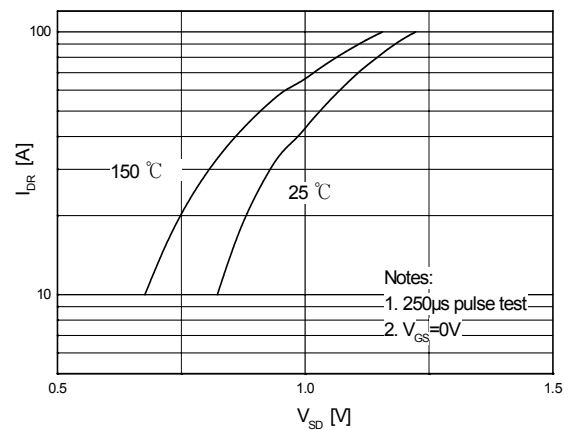
Transfer Characteristics



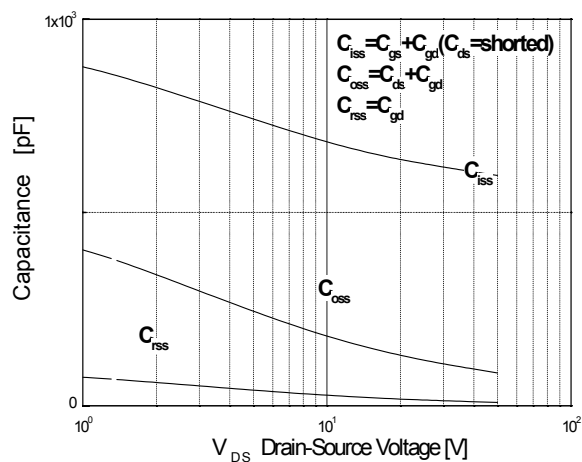
On-Resistance Variation vs. Drain Current and Gate Voltage



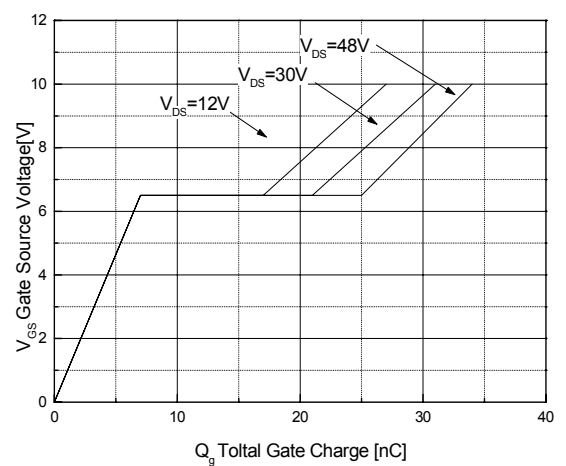
Body Diode Forward Voltage Variation vs. Source Current and Temperature



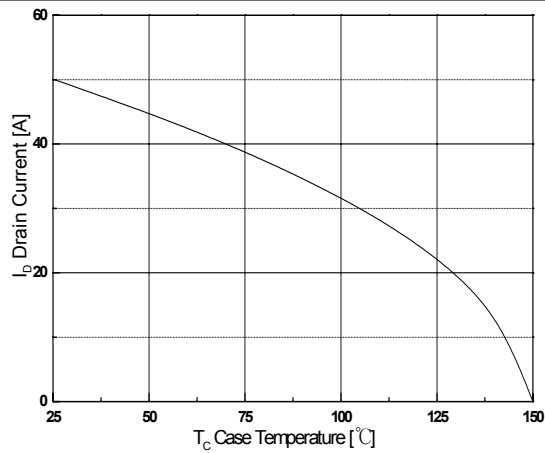
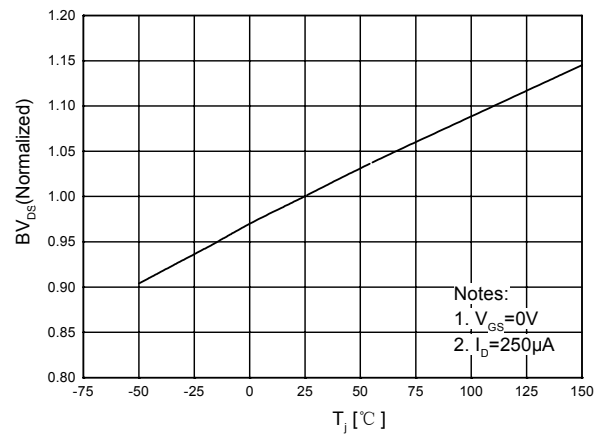
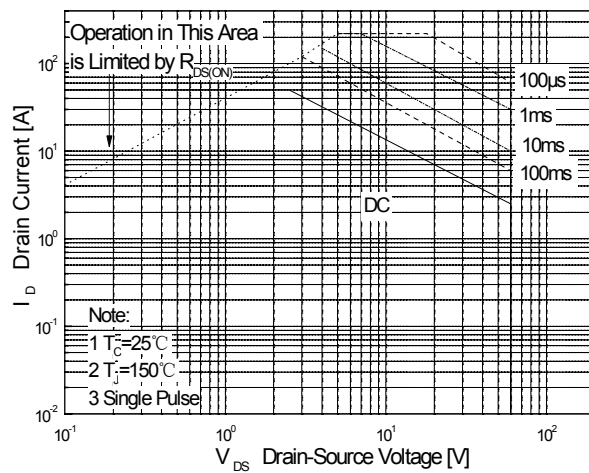
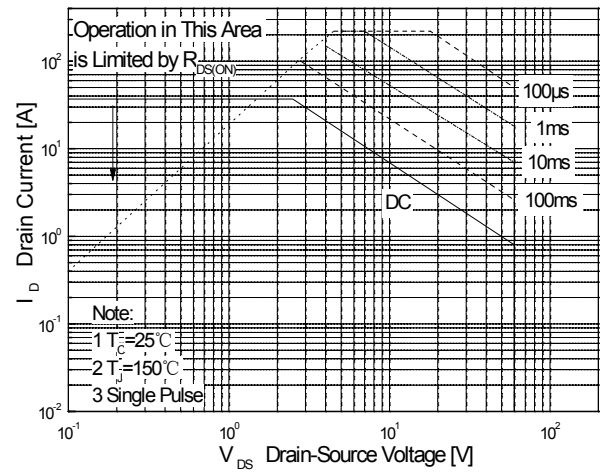
Capacitance Characteristics



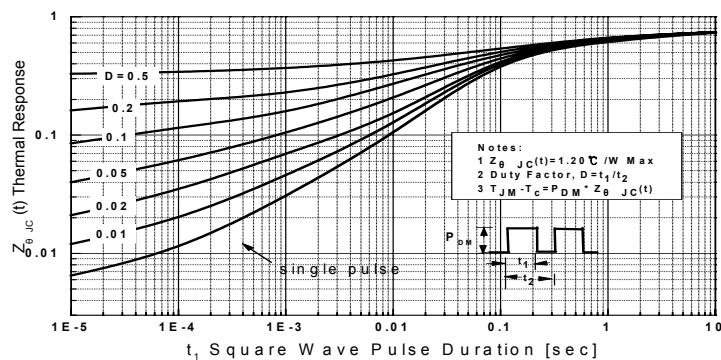
Gate Charge Characteristics



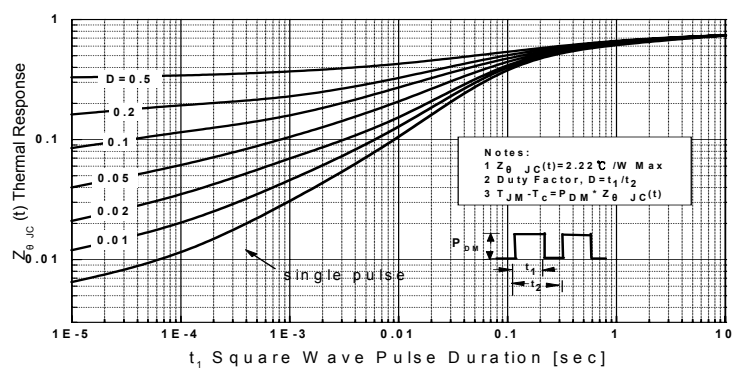
特征曲线 ELECTRICAL CHARACTERISTICS (curves)

Maximum Drain Current
vs. Case TemperatureBreakdown Voltage Variation
vs. TemperatureMaximum Safe Operating Area
55N06C/DMaximum Safe Operating Area
55N06F

Transient Thermal Response Curve 55N06C/D



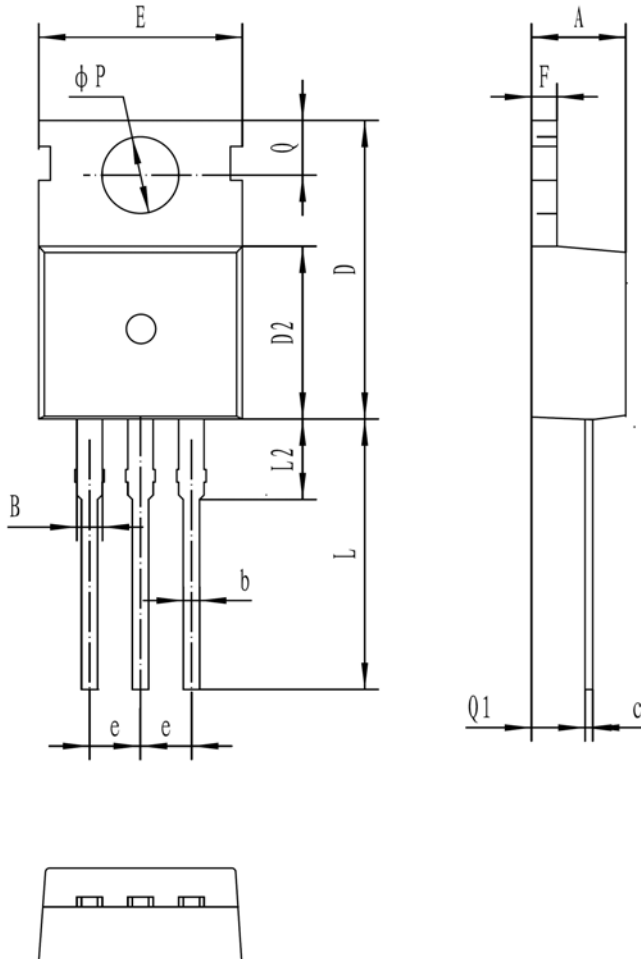
Transient Thermal Response Curve 55N06F



外形尺寸 PACKAGE MECHANICAL DATA

TO-220C

单位 Unit: mm

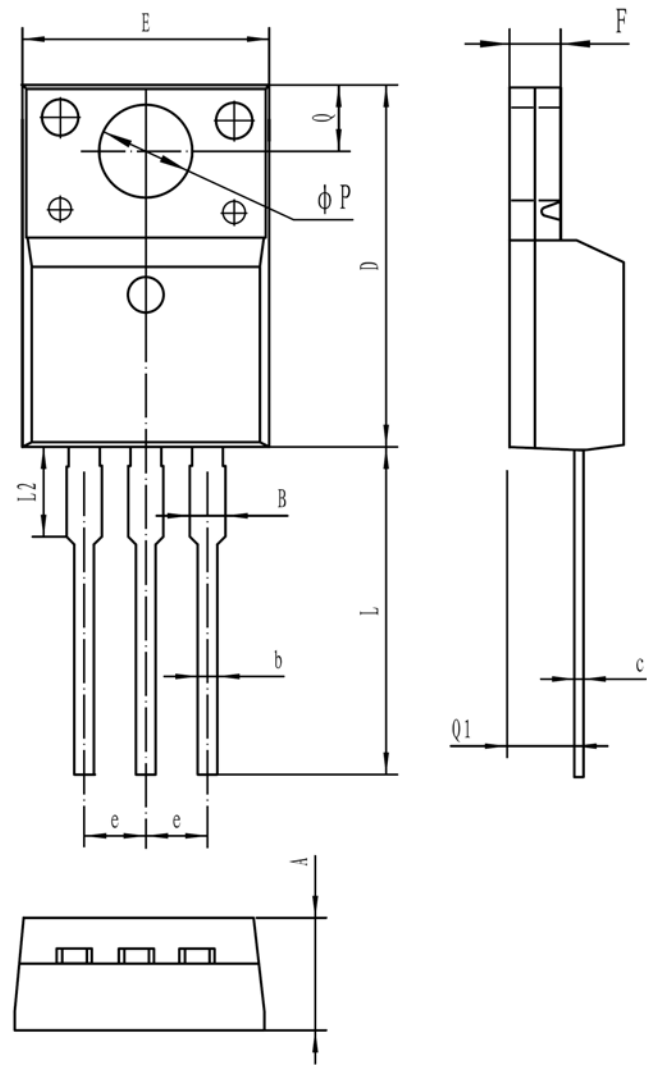


符号 symbol	MIN	MAX
A	4.30	4.70
B	1.10	1.40
b	0.70	0.95
c	0.40	0.65
D	15.20	16.20
D2	9.00	9.40
E	9.70	10.10
e	2.39	2.69
F	1.25	1.40
L	12.60	13.60
L2	2.80	3.20
Q	2.60	3.00
Q1	2.20	2.60
P	3.50	3.80

外形尺寸 PACKAGE MECHANICAL DATA

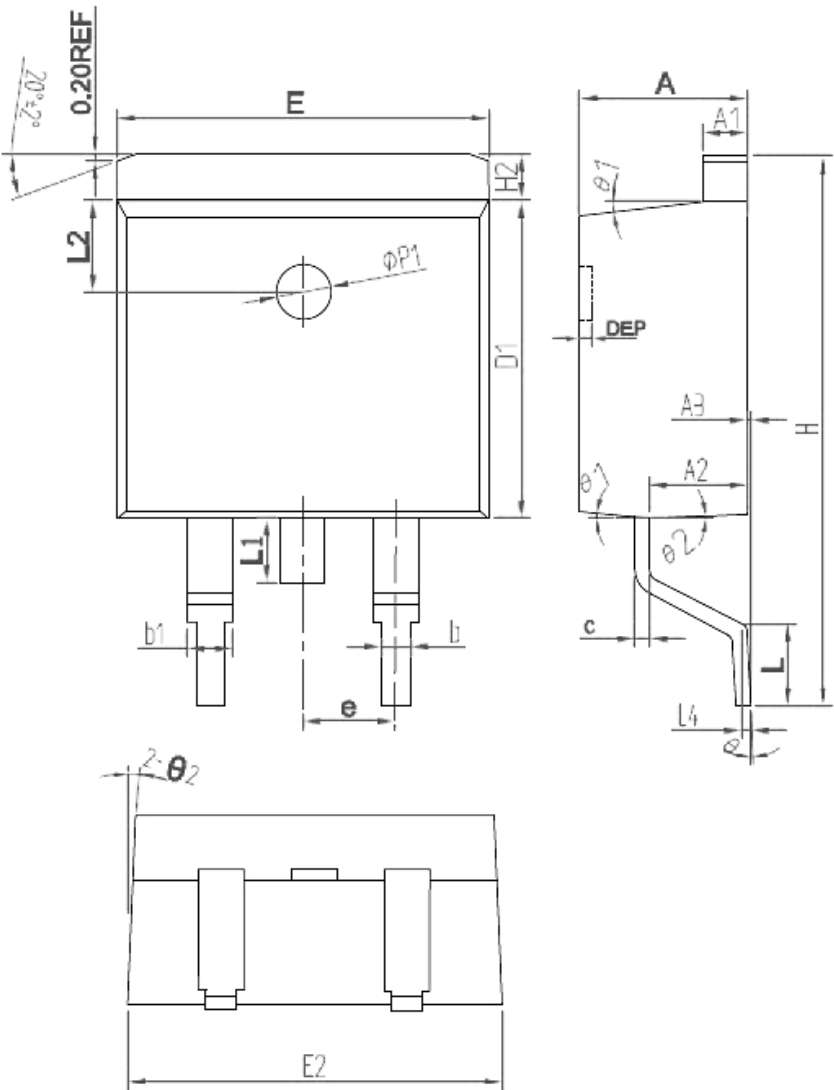
TO-220F

单位 Unit: mm



符 号 Symbol	MIN	MAX
A	4.5	4.9
B	-	1.47
b	0.7	0.9
c	0.45	0.6
D	15.67	16.07
E	9.96	10.36
e	2.54TYPE	
F	2.34	2.74
L	12.58	13.38
L2	3.13	3.33
ΦP	3.08	3.28
Q	3.2	3.4
Q1	2.56	2.96

外形尺寸 PACKAGE MECHANICAL DATA
TO-263



SYMBOL	MM		
	MIN	NOM	MAX
*A	4.40	4.57	4.70
*A1	1.22	1.27	1.32
A2	2.59	2.69	2.79
*A3	0.00		0.10
*b	0.77	0.813	0.90
b1	1.20	1.270	1.36
*c	0.34	0.381	0.47
*D1	8.60	8.70	8.80
*E	10.00	10.16	10.26
E2	10.00	10.10	10.20
*e	2.54 BSC		
*H	14.70	15.10	15.50
H2	1.17	1.27	1.40
*L	2.00	2.30	2.60
L1	1.45	1.55	1.70
L2	2.5 REF		
L4	0.25 BSC		
θ	0°	5°	8°
θ1	5°	7°	9°
θ2	1°	3°	5°
ΦP1	1.40	1.50	1.60
DEP	0.05	0.10	0.20